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NPN SILICON GERMANIUM RF TRANSISTOR **NESG260234**

NPN SIGE RF TRANSISTOR FOR MEDIUM OUTPUT POWER AMPLIFICATION (1 W) 3-PIN POWER MINIMOLD (34 PKG)

FEATURES

- This product is suitable for medium output power (1 W) amplification
 - $P_{out} = 30 \text{ dBm TYP.} @ V_{CE} = 6 \text{ V}, P_{in} = 15 \text{ dBm}, f = 460 \text{ MHz}$
 - $P_{out}=30\;dBm\;TYP.\; @\;V_{CE}=6\;V,\;P_{in}=20\;dBm,\;f=900\;MHz$
- MSG (Maximum Stable Gain) = 23 dB TYP. @ Vce = 6 V, Ic = 100 mA, f = 460 MHz
- Using UHS2-HV process (SiGe technology), Vсво (ABSOLUTE MAXIMUM RATINGS) = 25 V
- 3-pin power minimold (34 PKG)

ORDERING INFORMATION

| Part Number | Order Number | Package | Quantity | Supplying Form |
|---------------|------------------|---|----------------------|--|
| NESG260234 | NESG260234-AZ | 3-pin power minimold (Pb-Free) ^{Note1, 2} | 25 pcs (Non reel) | Magazine case |
| NESG260234-T1 | NESG260234-T1-AZ | | 1 kpcs/reel | 12 mm wide embossed tapingPin 2 (Emitter) face the perforation side of the tape |

Notes 1. Contains Lead in the part except the electrode terminals.

2. With regards to terminal solder (the solder contains lead) plated products (conventionally plated), contact

your nearby sales office.

Remark To order evaluation samples, contact your nearby sales office. Unit sample quantity is 25 pcs.

ABSOLUTE MAXIMUM RATINGS (TA = +25°C)

| Parameter | Symbol | Ratings | Unit |
|------------------------------|-----------|-------------|------|
| Collector to Base Voltage | Vсво | 25 | V |
| Collector to Emitter Voltage | VCEO | 9.2 | V |
| Emitter to Base Voltage | Vebo | 2.8 | V |
| Collector Current | lc | 600 | mA |
| Total Power Dissipation | Ptot Note | 1.9 | W |
| Junction Temperature | Tj | 150 | °C |
| Storage Temperature | Tstg | -65 to +150 | °C |

Note Mounted on 34.2 cm² \times 0.8 mm (t) glass epoxy PWB

Caution: Observe precautions when handling because these devices are sensitive to electrostatic discharge

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.

THERMAL RESISTANCE (TA = +25°C)

| Parameter | Symbol | Ratings | Unit |
|---|--------------------|---------|------|
| Termal Resistance from Junction to Ambient Note | Rth _{j-a} | 65 | °C/W |

Note Mounted on 34.2 $\text{cm}^2 \times 0.8 \text{ mm}$ (t) glass epoxy PWB

RECOMMENDED OPERATING RANGE (TA = +25°C)

| Parameter | Symbol | MIN. | TYP. | MAX. | Unit |
|------------------------------|--------|------|------|------|------|
| Collector to Emitter Voltage | VCE | - | 6.0 | 7.2 | V |
| Collector Current | lc | - | 400 | 500 | mA |
| Input Power Note | Pin | - | 15 | 20 | dBm |

Note Input power under conditions of $V_{\text{CE}} \leq 6.0~\text{V},~\text{f} = 460~\text{MHz}$

ELECTRICAL CHARACTERISTICS (T_A = +25°C)

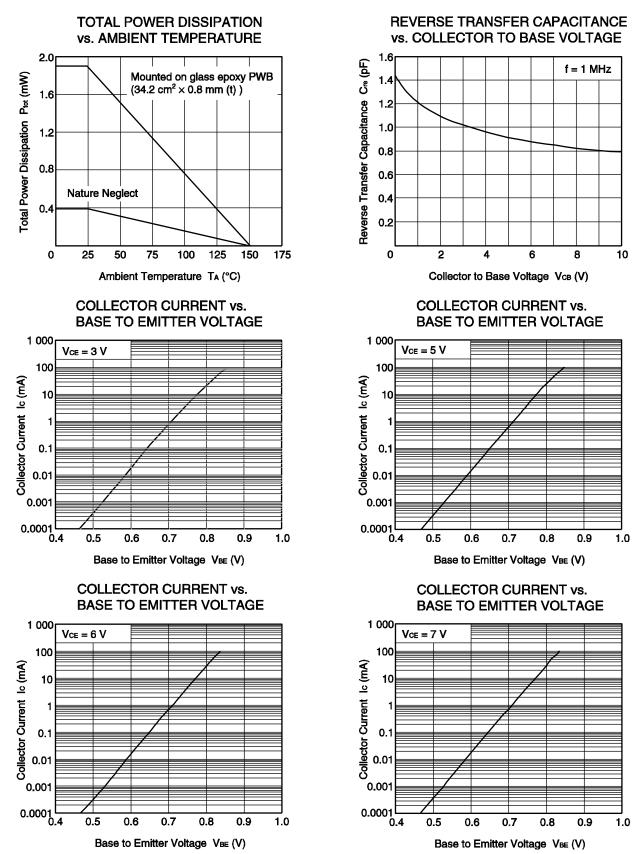
| Parameter | Symbol | Test Conditions | MIN. | TYP. | MAX. | Unit |
|---------------------------|----------|---|------|------|------|------|
| DC Characteristics | | | | | | |
| Collector Cut-off Current | Ісво | $V_{CB} = 9.2 \text{ V}, I_E = 0 \text{ mA}$ | - | - | 1 | μA |
| Emitter Cut-off Current | Іево | VEB = 1.0 V, Ic = 0 mA | - | _ | 1 | μA |
| DC Current Gain | hfe Note | Vce = 3 V, lc = 100 mA | 80 | 120 | 180 | _ |
| RF Characteristics | | · | | | | |
| Linner Gain (1) | G∟ | $V_{\text{CE}} = 6 \text{ V}, \text{ Ic } (\text{set}) = 30 \text{ mA (RF OFF)},$ | 19 | 22 | _ | dB |
| | | $f = 460 \text{ MHz}, P_{in} = 0 \text{ dBm}$ | | | | |
| Linner Gain (2) | G∟ | $V_{\text{CE}} = 6 \text{ V}, \text{ Ic } (\text{set}) = 30 \text{ mA } (\text{RF OFF}),$ | - | 19 | - | dB |
| | | $f = 900 \text{ MHz}, P_{in} = 0 \text{ dBm}$ | | | | |
| Output Power (1) | Pout | $V_{\text{CE}}=6~\text{V},~\text{Ic}~(\text{set})=30~\text{mA}~(\text{RF}~\text{OFF}),$ | 28.5 | 30.0 | - | dBm |
| | | f = 460 MHz, Pin = 15 dBm | | | | |
| Output Power (2) | Pout | $V_{\text{CE}}=6~\text{V},~\text{Ic}~(\text{set})=30~\text{mA}~(\text{RF}~\text{OFF}),$ | - | 30.0 | - | dBm |
| | | f = 900 MHz, P _{in} = 20 dBm | | | | |
| Collector Efficiency (1) | ηс | $V_{\text{CE}} = 6 \text{ V}, \text{ Ic }_{(\text{set})} = 30 \text{ mA (RF OFF)},$ | _ | 50 | _ | % |
| | | f = 460 MHz, P _{in} = 15 dBm | | | | |
| Collector Efficiency (2) | ηс | $V_{\text{CE}} = 6 \text{ V}, \text{ Ic }_{(\text{set})} = 30 \text{ mA (RF OFF)},$ | _ | 60 | _ | % |
| | - | f = 900 MHz, P _{in} = 20 dBm | | | | |

Note Pulse measurement: PW \leq 350 μ s, Duty Cycle \leq 2%

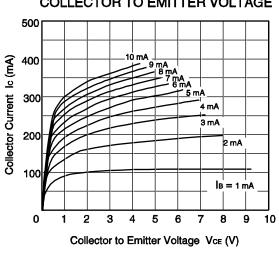
hfe CLASSIFICATION

| Rank | FB | | |
|-----------|-----------|--|--|
| Marking | SP | | |
| hfe Value | 80 to 180 | | |

TYPICAL CHARACTERISTICS (TA = +25°C, unless otherwise specified)

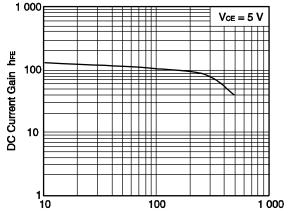


Remark The graphs indicate nominal characteristics.



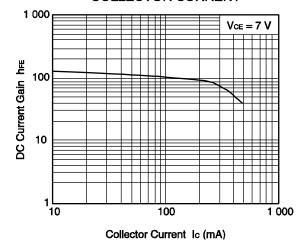
COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE

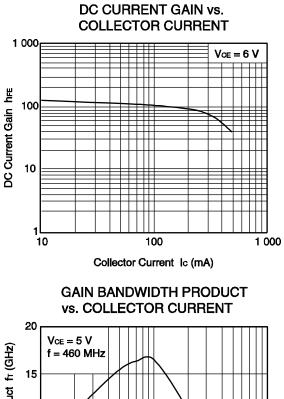


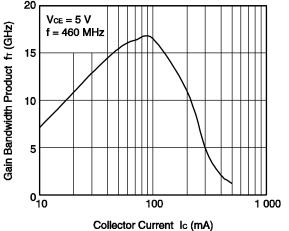


Collector Current Ic (mA)

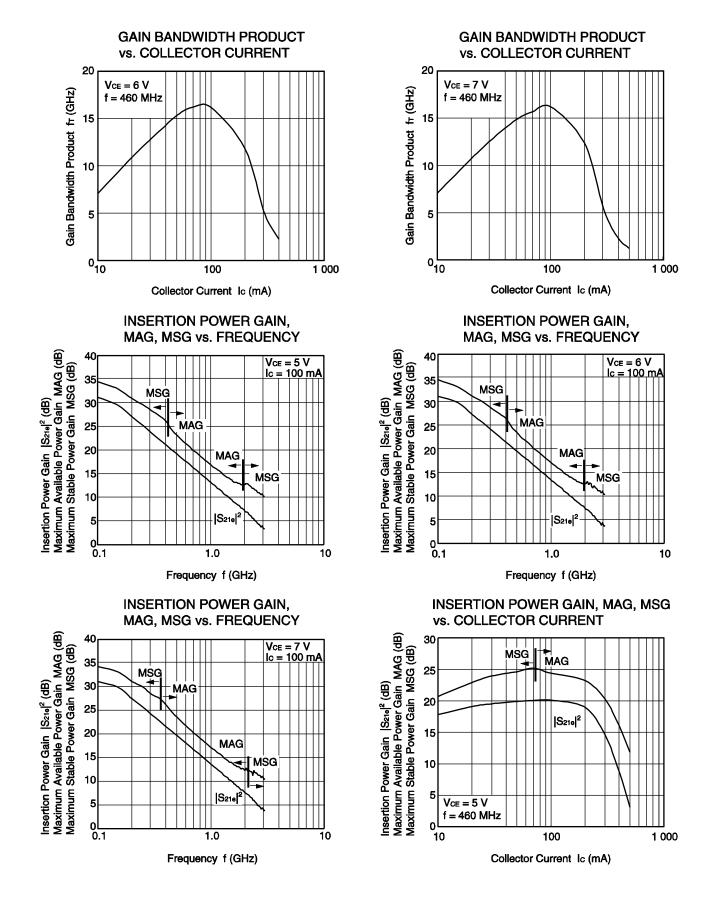




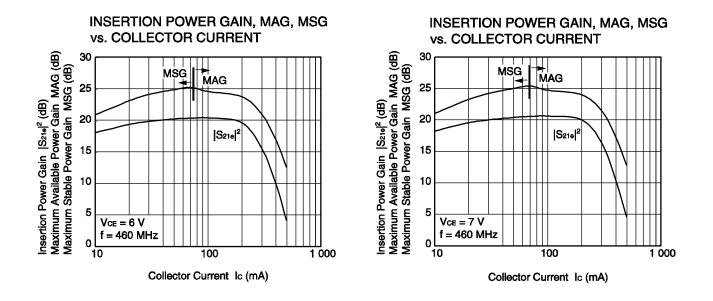




Remark The graphs indicate nominal characteristics.



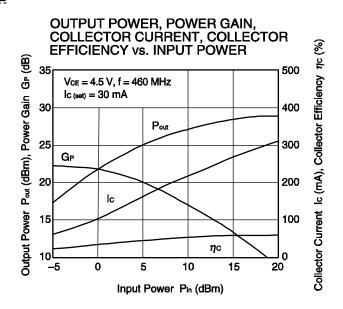
Remark The graphs indicate nominal characteristics.

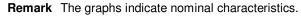


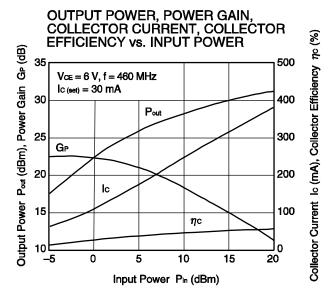
S-PARAMETERS

- S-parameters and noise parameters are provided on our Web site in a format (S2P) that enables the direct import of the parameters to microwave circuit simulators without the need for keyboard inputs.
- · Click here to download S-parameters.
- [RF and Microwave] ® [Device Parameters]
- · URL http://www.necel.com/microwave/en/

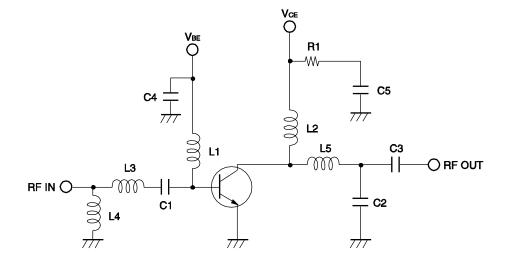
PA EVALUATION CIRCUIT TYPICAL CHARACTERISTICS





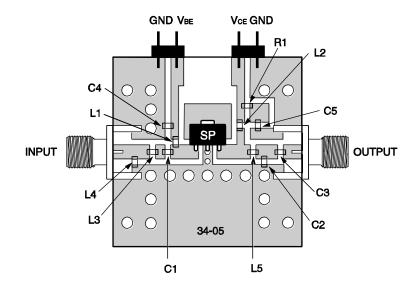


● EVALUATION CIRCUIT (f = 460 MHz)



The application circuits and their parameters are for reference only and are not intended for use in actual design-ins.

EVALUATION BOARD (f = 460 MHz)



Notes

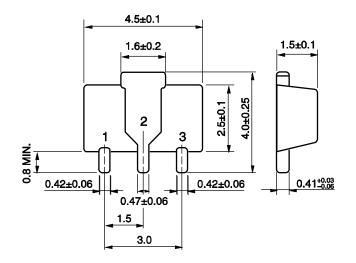
- 1. 20×20 mm, t = 0.8 mm double sided copper clad glass epoxy PWB.
- 2. Back side: GND pattern
- 3. Solder gold plated on pattern
- 4. ∘O: Through holes

COMPONENT LIST

| Component | Maker | Value | Size (TYPE) | Purpose |
|-----------|--------|--------------|-------------|-----------------------------------|
| C1 | Murata | 10 pF | 1005 | Input DC Block/Input RF Matching |
| C2 | Murata | 4 pF | 1005 | Input RF Matching |
| C3 | Murata | 33 pF | 1005 | Input DC Block/Output RF Matching |
| C4 | Murata | 10 000 pF | 1005 | RF GND |
| C5 | Murata | 1 <i>µ</i> F | 1608 | RF GND |
| L1 | Toko | 68 nH | 1005 | RF Block/Input RF Matching |
| L2 | Toko | 33 nH | LLQ2021 | RF Block/Output RF Matching |
| L3 | Toko | 1 nH | 1005 | Input RF Matching |
| L4 | Toko | 8.2 nH | 1005 | Input RF Matching |
| L5 | Toko | 8.2 nH | LLQ2021 | Output RF Matching |
| R1 | SSM | 15 Ω | 1608 | Improve Stability |

PACKAGE DIMENSIONS

3-PIN POWER MINIMOLD (34 PKG) (UNIT: mm)



PIN CONNECTIONS

- 1. Collector
- 2. Emitter
- 3. Base